



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#16/A
6/25/02
OKI.206
J. Ho

In re PATENT APPLICATION of

Masahiro Yoshida et al.

Group Art Unit: 2818

Serial No.: 09/759,639

Examiner: T. Ho

Filed: January 16, 2001

For: SEMICONDUCTOR DEVICE AND METHOD FOR MANUFACTURING THE
SAME (To be Amended)

RECEIVED

JUN 24 2002
TECHNOLOGY CENTER 2800

AMENDMENT

Honorable Assistant Commissioner for Patents
Washington, D.C. 20231

Date: June 14, 2002

Sir:

In response to the Office Action dated January 14, 2002, the period for response having been extended two (2) months to June 14, 2002, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

In the Title:

Please amend the title to read --SEMICONDUCTOR DEVICE HAVING A THICK OXIDE LAYER UNDER GATE SIDE WALLS AND METHOD FOR MANUFACTURING THE SAME--.

In the Specification:

Replace the paragraph beginning on page 1, line 10 with the following paragraph:

A